Unit in mm

TOSHIBA FIELD EFFECT TRANSISTOR SILICON N CHANNEL JUNCTION TYPE

2 S K 3 6 5

FOR AUDIO AMPLIFIER, ANALOG-SWITCH, CONSTANT CURRENT AND IMPEDANCE CONVERTER APPLICATIONS

High Breakdown Voltage : V_{GDS} = −50V

• High Imput Impedance : IGSS = -1.0nA (Max.)

 $(V_{GS} = -30V)$

• Low $R_{DS(ON)}$: $R_{DS(ON)} = 80\Omega \text{ (Typ.)}$

 $(I_{DSS} = 5mA)$

• Small Package

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Gate-Drain Voltage	v_{GDS}	-50	V
Gate Current	$I_{\mathbf{G}}$	10	mA
Drain Power Dissipation	$P_{\mathbf{D}}$	200	mW
Junction Temperature	T_{j}	125	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	$^{\circ}\mathrm{C}$

Weight: 0.13g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

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CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Cut-off Current	IGSS	$V_{GS} = -30V, V_{DS} = 0$	_		-1.0	nA
Gate-Drain Breakdown Voltage	V (BR) GDS	$V_{DS} = 0, I_G = -100 \mu A$	-50		_	V
Drain Current	I _{DSS} (Note 1)	$V_{DS} = 10V, V_{GS} = 0$	1.2		14	mA
Gate-Source Cut-off Voltage	V _{GS} (OFF)	$V_{ m DS} = 10 { m V}, \ { m I}_{ m D} = 0.1 \mu { m A}$	-0.25	_	-1.5	V
Forward Transfer Admittance	$ Y_{fs} $	$ m V_{DS}$ =10V, $ m V_{GS}$ =0, f=1kHz (Note 2)	5.0	19	_	mS
Input Capacitance	$\mathrm{c}_{\mathrm{iss}}$	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz$	_	13	_	pF
Reverse Transfer Capacitance	C_{rss}	$V_{ m DG} = 10 V, \; I_{ m D} = 0, \; f = 1 { m MHz}$	_	3	_	pF
Drain-Source ON Resistance	R _{DS} (ON)	$V_{DS}=10$ mV, $V_{GS}=0$ (Note 2)	_	80	_	Ω

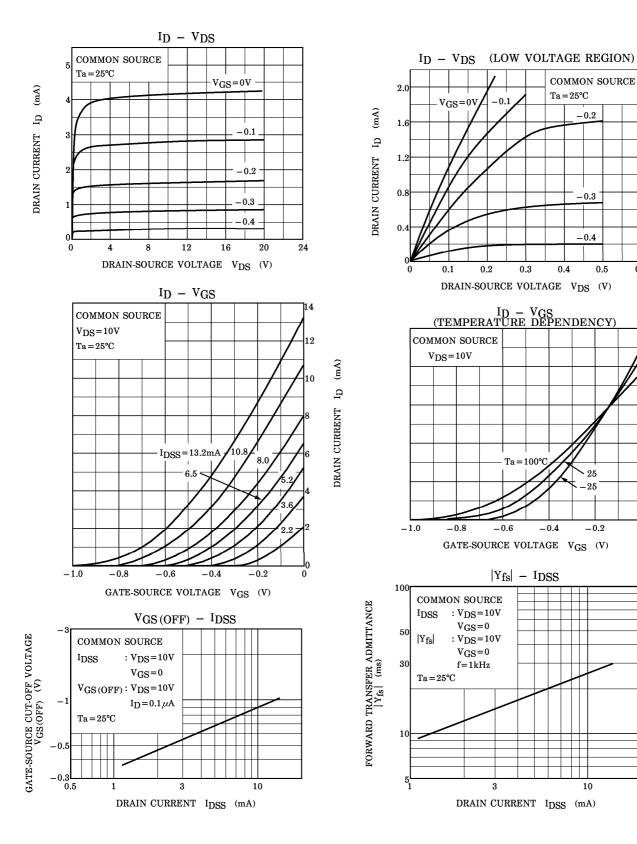
Note 1 : IDSS Classification Y : 1.2~3.0mA, GR : 2.6~6.5mA, BL : 6~14mA

Note 2: Condition of the typical Value IDSS=5mA

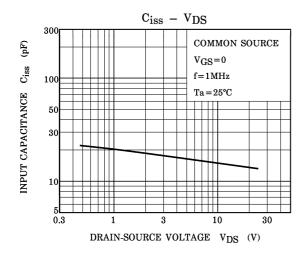
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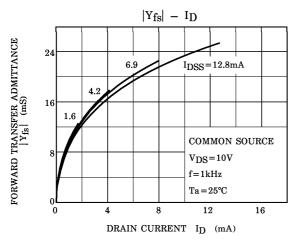
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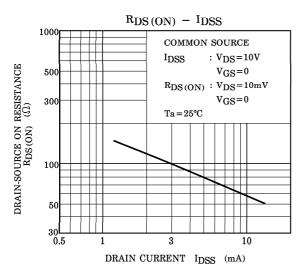
DRAIN CURRENT ID (mA)

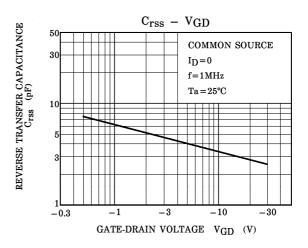


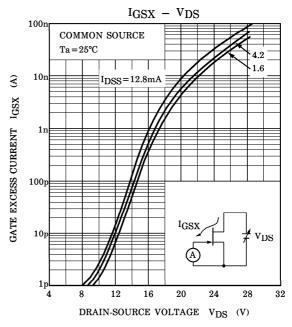
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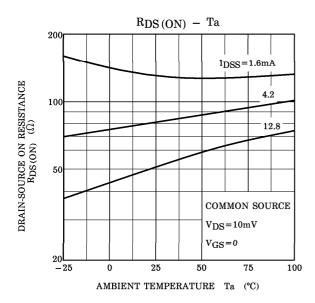


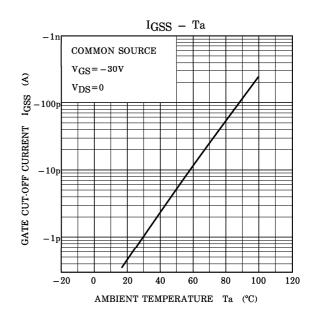


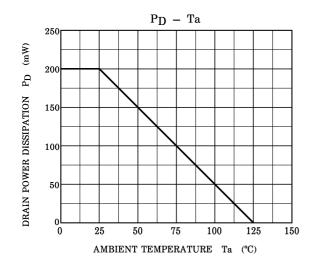




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